

isc Silicon NPN Power Transistor

DESCRIPTION

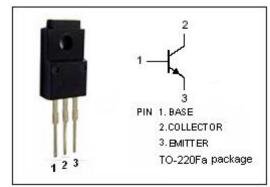
- · High Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 400V (Min)
- · High Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

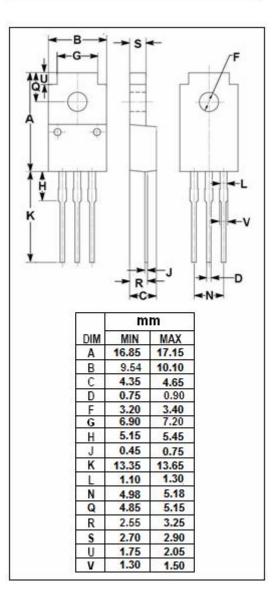
APPLICATIONS

- · Switching regulator and high voltage switching applications.
- · High speed DC-DC converter applications.



SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	500	V	
Vceo	Collector-Emitter Voltage	400	V	
V _{EBO}	Emitter-Base Voltage	7	V	
Ic	Collector Current-Continuous	5	А	
Ісм	Collector Current-Peak	7	А	
I _B	Base Current-Continuous	1	А	
P _C	Collector Power Dissipation @ T _c =25℃	30	W	
	Collector Power Dissipation @ T _a =25℃	2		
TJ	Junction Temperature	150	°C	
T _{stg}	Storage Temperature Range	-55~150	°C	







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2SC3310

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

1c-25 C unless otherwise specified									
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT			
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	I _C = 10mA ; I _B = 0	400			٧			
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 1mA ; I _E = 0	500			V			
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 5A; I _B = 1A			1.0	V			
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 5A; I _B = 1A			1.5	V			
Ісво	Collector Cutoff Current	V _{CB} = 400V; I _E = 0			100	μА			
I _{EBO}	Emitter Cutoff Current	V _{EB} = 7V; I _C = 0			1	mA			
h _{FE-1}	DC Current Gain	I _C = 3A ; V _{CE} = 5V	12						
h _{FE-2}	DC Current Gain	Ic= 5A; Vc= 5V	8						
Switching times									
t _r	Rise Time				1.0	μ \$			
t _{stg}	Storage Time	I _{B1} = -I _{B2} = 0.4A R _L = 50 Ω ;V _{CC} ≈200V P _W =20 μ s;Duty Cycle≤1%			2.5	μ S			
t _f	Fall Time				1.0	μ S			

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